High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Absolute Maximum Ratings

(Voltages referenced to GND.)	
V _{CC}	0.3V to +6.0V
R0	-0.3V to (V _{CC} + 0.3V)
RE, DE, DI	0.3V to +6.0V
A, B (V _{CC} ≥ 3.6V)	8.0V to +13.0V
A, B (V _{CC} < 3.6V)	9.0V to +13.0V
Short-Circuit Duration (RO, A, B) to GND.	Continuous
Operating Temperature Range	
MAX14783EE	40°C to +85°C
MAX14783EA	40°C to +125°C

Junction Temperature+150	J∘C
Storage Temperature Range65°C to +150	J∘C
Continuous Power Dissipation (T _A = +70°C)	
µMAX (derate at 4.8mW/°C above +70°C)	nW
SO (derate at 7.6mW/°C above +70°C)606r	nW
TDFN-EP (derate at 24.4mW/°C above +70°C)1951r	nW
Lead Temperature (soldering, 10s)+300	О₀С
Soldering Temperature (reflow) +260	J∘C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

PACKAGE TYPE: 8 SOIC					
Package Code	S8+4				
Outline Number	21-0041				
Land Pattern Number	90-0096				
THERMAL RESISTANCE, FOUR-LAYER BOARD					
Junction to Ambient (θ_{JA})	132°C/W				
Junction to Case (θ _{JC})	38°C/W				

PACKAGE TYPE: 8 TDFN					
Package Code	T833+2				
Outline Number	21-0137				
Land Pattern Number	90-0059				
THERMAL RESISTANCE, FOUR-LAYER BOARD					
Junction to Ambient (θ_{JA})	41°C/W				
Junction to Case (θ _{JC})	8°C/W				

PACKAGE TYPE: 8 µMAX					
Package Code	U8+1				
Outline Number	<u>21-0036</u>				
Land Pattern Number	90-0092				
THERMAL RESISTANCE, FOUR-LAYER BOARD					
Junction to Ambient (θ_{JA})	206°C/W				
Junction to Case (θ _{JC})	42°C/W				

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Electrical Characteristics

(V_{CC} = +3.0V to +5.5V, T_A = T_{MIN} to T_{MAX} , unless otherwise specified. Typical values are at V_{CC} = +5V and T_A = +25°C.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
POWER SUPPLY (Test)							
Supply Voltage	V _{CC}			3.0		5.5	V
Supply Current	ICC	DE = V _{CC} , RE = GND, no	load		1.9	4	mA
Shutdown Supply Current	ISHDN	DE = GND, \overline{RE} = V _{CC}				10	μA
DRIVER							
		V _{CC} = 4.5V, R _L = 54Ω, Fig	gure 1	2.1			
Differential Driver Output	V _{OD}	V_{CC} = 3V, R _L = 100 Ω , Fig	ure 1	2.0			V
		V_{CC} = 3V, R _L = 54 Ω , Figu	re 1	1.5			
Change in Magnitude of Differential Output Voltage	ΔV _{OD}	R_L = 54Ω or 100Ω, Figure	1 (Note 3)	-0.2	0	+0.2	V
Driver Common-Mode Output Voltage	V _{OC}	R _L = 54Ω or 100Ω, Figure	1		V _{CC} / 2	3	V
Change in Magnitude of Common- Mode Voltage	ΔV _{OC}	R_L = 54Ω or 100Ω, Figure 1 (Note 3)		-0.2		+0.2	V
Single-Ended Driver Output High	VOH	A or B output, $I_{A \text{ or } B} = -20$	mA	2.2			V
Single-Ended Driver Output Low	V _{OL}	A or B output, I _{A or B} = 20r	mA			0.8	V
Differential Output Capacitance	COD	$DE = \overline{RE} = V_{CC}$, f = 4MHz			12		pF
Driver Short-Circuit Output Current	llostl	$0 \le V_{OUT} \le +12V$, output low				250	mA
Diver Short-Circuit Output Current	POST	$-7V \le V_{OUT} \le V_{CC}$, output	high			250	mA
RECEIVER							
Input Current	I _{A, B}	DE = GND, V _{CC} = GND or +5.5V	V _{IN} = +12V V _{IN} = -7V	-800	400	1000	μA
Differential Input Capacitance	C _{A, B}	Between A and B, DE = G			12		pF
Receiver Differential Threshold Voltage	V _{TH}	$-7V \le V_{CM} \le +12V$		-200	-105	-10	mV
Receiver Input Hysteresis	ΔV _{TH}	V _{CM} = 0V			10		mV
Receiver Input Resistance	R _{IN}	$-7V \le V_{CM} \le +12V$		12			kΩ
LOGIC INTERFACE (DI, DE, RE, RO				1			1
Input Voltage High	VIH	DE, DI, RE		2.0			V
Input Voltage Low	VIL	DE, DI, RE				0.8	V
Input Hysteresis	V _{HYS}	DE, DI, RE			50		mV
Input Current	IIN	DE, DI, RE				±1	μA
Input Impedance on First Transition		DE, RE		1		10	kΩ
RO Output Voltage High	VOHRO	$\overline{RE} = GND, \ I_{RO} = -2mA, \\ (V_{A} - V_{B}) > 200mV$		V _{CC} - 0.4			V
RO Output Voltage Low	V _{OLRO}	$\overline{\text{RE}}$ = GND, I _{RO} = 2mA, (V _A - V _B) < -200mV				0.4	V

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Electrical Characteristics (continued)

 $(V_{CC} = +3.0V \text{ to } +5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.)$ (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Receiver Tri-State Output Current	I _{OZR}	$\overline{RE} = V_{CC}, \ 0 \le V_{RO} \le V_{CC}$			±1	μA
Receiver Output Short-Circuit Current	IOSR	$0 \le V_{RO} \le V_{CC}$			±110	mA
PROTECTION						
Thermal Shutdown Threshold	TSHDN	Temperature rising		+160		°C
Thermal Shutdown Hysteresis				15		°C
		IEC 61000-4-2 Air Gap Discharge to GND		±20		
ESD Protection on A and B Pins		IEC 61000-4-2 Contact Discharge to GND		±12		kV
		Human Body Model		±35		
ESD Protection, All Other Pins		Human Body Model		±2		kV

Switching Characteristics MAX14783E

 $(V_{CC} = +3V \text{ to } +5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.)$ (Notes 1, 2, 4)

PARAMETER	SYMBOL	COND	ITIONS	MIN	ТҮР	MAX	UNITS
DRIVER	,						
Driver Propagation Delay	^t DPLH	R _L = 54Ω, C _L = 5	$R_L = 54\Omega$, $C_L = 50pF$, Figures 2 and 3			20	ns
	^t DPHL	Figures 2 and 3				20	115
Driver Differential Output Rise or Fall Time	t _{HL} , t _{LH}	$R_L = 54\Omega, C_L = 5$ Figures 2 and 3	0pF,			7	ns
Differential Driver Output Skew t _{DPLH} - t _{DPHL}	^t DSKEW	$R_L = 54\Omega$, $C_L = 5$ Figures 2 and 3 (3	ns
		MAX14783EATA				42	
		MAX14783EEUA				30	
		MAX14783EESA				40	
		MAX14783EAUA	3.0V ≤ V _{CC} ≤ 3.6V			42	
Maximum Data Rate	DR _{MAX}		3.0V ≤ V _{CC} ≤ 5.5V			6	Mbps
			3.0V ≤ V _{CC} ≤ 3.6V			42	
		MAX14783EASA	3.0V ≤ V _{CC} ≤ 5.5V			16	

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Switching Characteristics MAX14783E (continued)

 $(V_{CC} = +3V \text{ to } +5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.)$ (Notes 1, 2, 4)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Driver Enable to Output High	^t DZH	$R_L = 110\Omega$, $C_L = 50pF$, Figures 4 and 5 (Note 6)			30	ns
Driver Enable to Output Low	^t DZL	$R_L = 110\Omega$, $C_L = 50pF$, Figures 4 and 5 (Note 6)			30	ns
Driver Disable Time from Low	^t DLZ	R_L = 110Ω, C_L = 50pF, Figures 4 and 5			30	ns
Driver Disable Time from High	^t DHZ	R_L = 110Ω, C_L = 50pF, Figures 4 and 5			30	ns
Driver Enable from Shutdown to Output High	^t DLZ(SHDN)	$R_L = 110\Omega$, $C_L = 15pF$, Figures 4 and 5 (Note 6)			6	μs
Driver Enable from Shutdown to Output Low	^t DHZ(SHDN)	R_L = 110Ω, C_L = 15pF, Figures 4 and 5 (Note 6)			6	μs
Time to Shutdown	^t SHDN	(Note 6)	50		800	ns
RECEIVER						
Receiver Propagation Delay	^t RPLH	$C_{L} = 15$ pF, Figures 6 and 7			25	nc
Receiver Propagation Delay	^t RPHL	$C_{L} = 13 \mu r$, Figures 6 and 7			25	ns
Receiver Output Skew	^t RSKEW	C _L = 15pF, Figures 6 and 7 (Note 5)			2	ns
Maximum Data Rate	DRMAX		42			Mbps
Receiver Enable to Output High	^t RZH	$R_L = 1k\Omega$, $C_L = 15pF$, Figure 8 (Note 6)			30	ns
Receiver Enable to Output Low	^t RZL	$R_L = 1k\Omega$, $C_L = 15pF$, Figure 8 (Note 6)			30	ns
Receiver Disable Time from Low	^t RLZ	$R_L = 1k\Omega$, $C_L = 15pF$, Figure 8			30	ns
Receiver Disable Time from High	^t RHZ	R _L = 1kΩ, C _L = 15pF, Figure 8			30	ns
Receiver Enable from Shutdown to Output High	^t RLZ(SHDN)	$R_L = 1k\Omega$, $C_L = 15pF$, Figure 8 (Note 6)			6	μs
Receiver Enable from Shutdown to Output Low	^t RHZ(SHDN)	$R_L = 1k\Omega$, $C_L = 15pF$, Figure 8 (Note 6)			6	μs
Time to Shutdown	^t SHDN	(Note 6)	50		800	ns

Note 1: All devices 100% production tested at $T_A = +25^{\circ}C$. Specifications over temperature are guaranteed by design.

Note 2: All currents into the device are positive; all currents out of the device are negative. All voltages are referenced to ground, unless otherwise noted.

Note 3: ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when the DI input changes state.

Note 4: Capacitive load includes test probe and fixture capacitance.

Note 5: Guaranteed by design; not production tested.

Note 6: The timing parameter refers to the driver or receiver enable delay, when the device has exited the initial hot-swap protect state and is in normal operating mode.

Note 7: Shutdown is enabled by driving RE high and DE low. The device is guaranteed to have entered shutdown after t_{SHDN} has elapsed.

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Test and Timing Diagrams

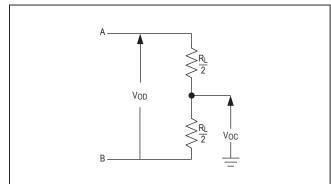


Figure 1. Driver DC Test Load

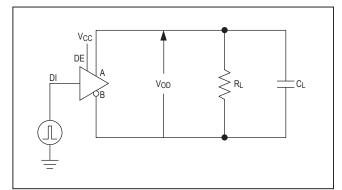


Figure 2. Driver Timing Test Circuit

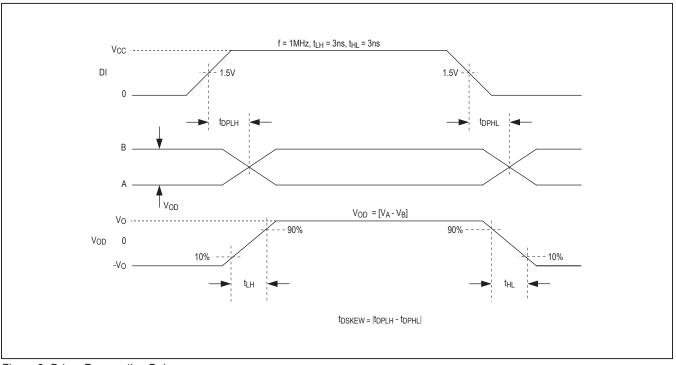


Figure 3. Driver Propagation Delays

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

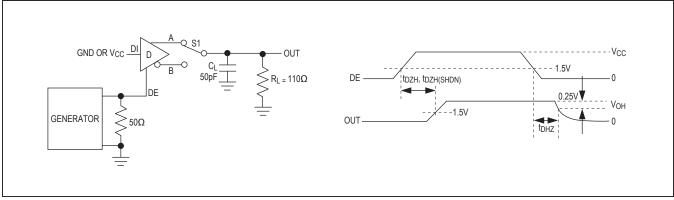


Figure 4. Driver Enable and Disable Times (t_{DZH}, t_{DHZ})

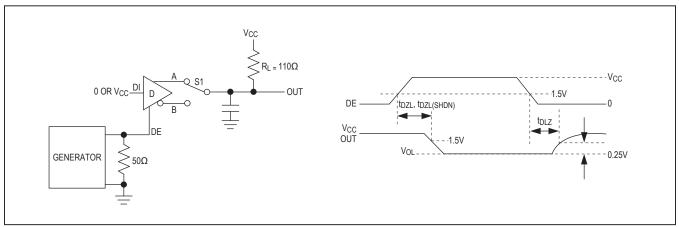


Figure 5. Driver Enable and Disable Times (t_{DZL}, t_{DLZ})

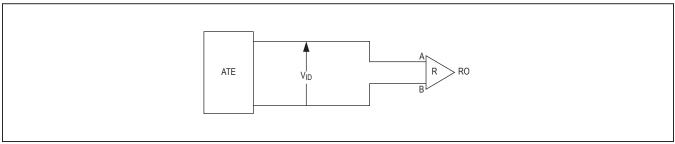


Figure 6. Receiver Propagation Delay Test Circuit

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

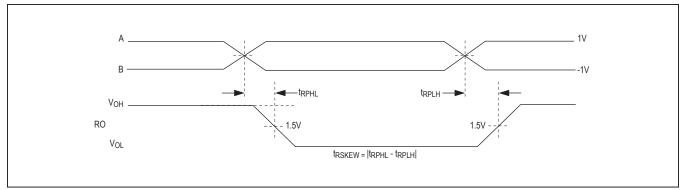


Figure 7. Receiver Propagation Delays

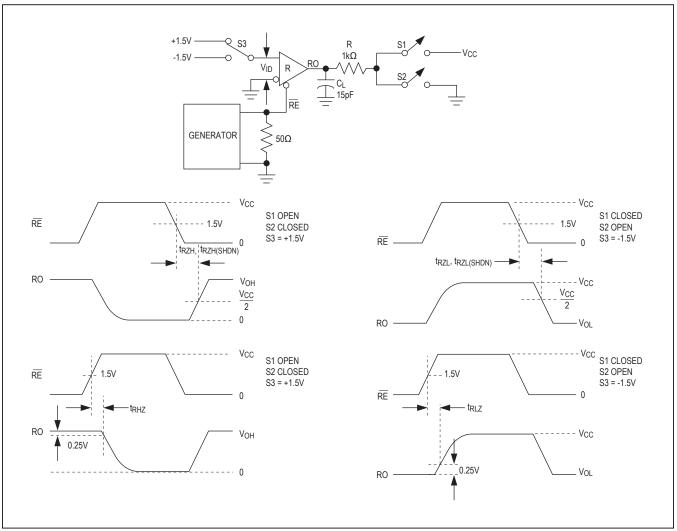
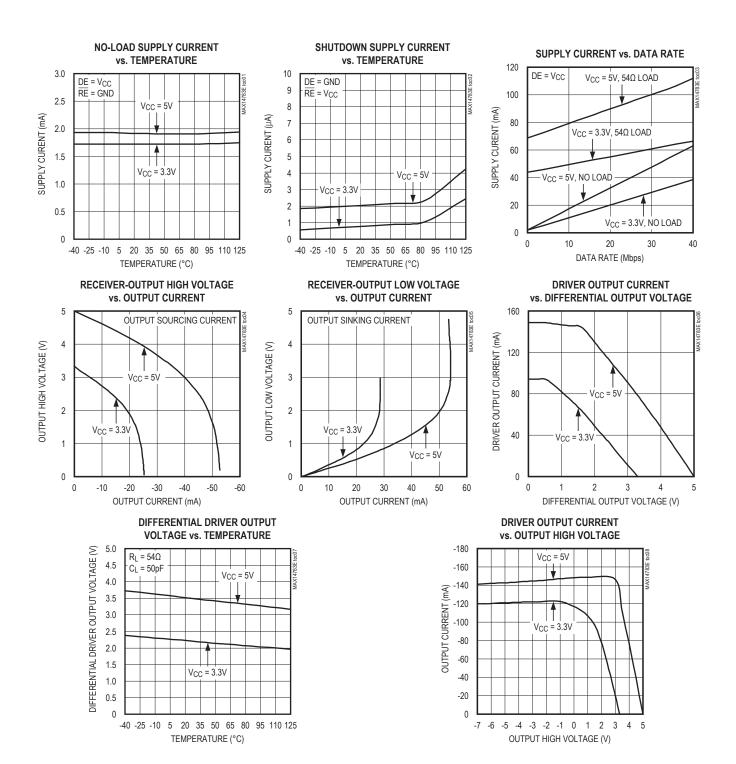


Figure 8. Receiver Enable and Disable Times

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Typical Operating Characteristics

(V_{CC} = +5V, T_A = +25°C, unless otherwise specified.)

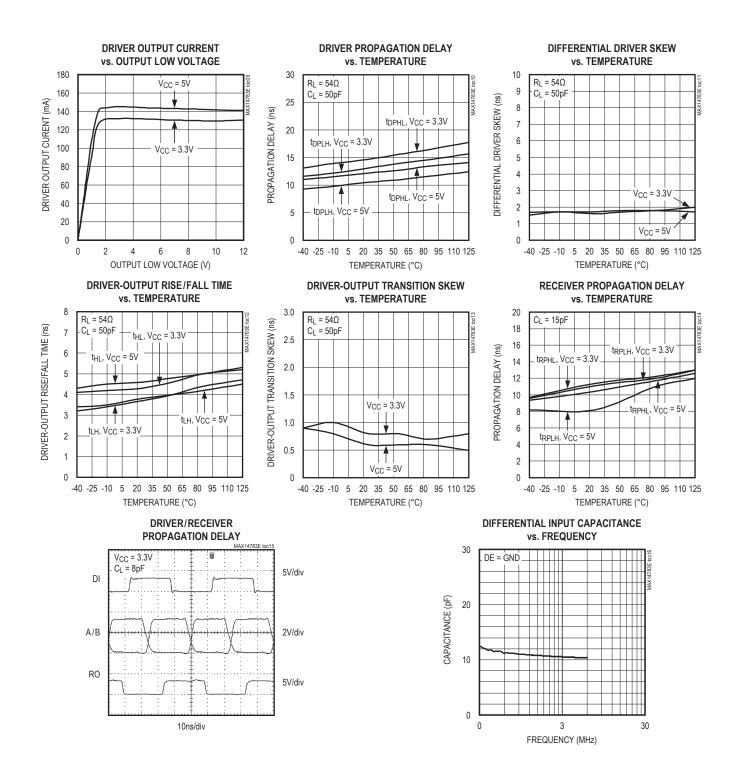


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High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Typical Operating Characteristics (continued)

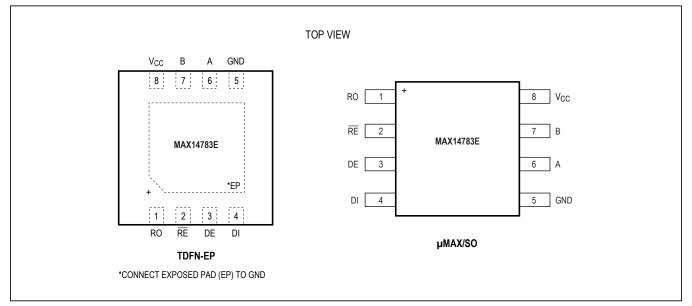
 $(V_{CC} = +3.0V \text{ to } +5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.)$ (Notes 1, 2)



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High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Pin Configuration



Pin Description

PIN	NAME	FUNCTION
1	RO	Receiver Output. See Function Tables.
2	RE	Receiver Output Enable. Drive \overline{RE} low to enable RO. Drive \overline{RE} high to disable the receiver. RO is high impedance when \overline{RE} is high. Drive \overline{RE} high and pull DE low to enter low-power shutdown mode.
3	DE	Driver Output Enable. Drive DE high to enable the driver. Drive DE low to disable the driver. Driver outputs are high-impedance when the driver is disabled. Drive RE high and pull DE low to enter low-power shutdown mode.
4	DI	Driver Input. With DE high, a low on DI forces the A output low and the B output high. Similarly, a high on DI forces the A output high and B output low.
5	GND	Ground
6	А	Noninverting RS-485/RS-422 Receiver Input and Driver Output
7	В	Inverting RS-485/RS-422 Receiver Input and Driver Output
8	V _{CC}	Positive Supply Voltage Input. Bypass V _{CC} with a 0.1µF ceramic capacitor to ground.
—	EP	Exposed Pad (TDFN only). Connect EP to GND.

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Function Tables

TRANSMITTING							
INPUTS			OUTPUTS				
RE	DE	DI	В	MODE			
Х	1	1	0 1		Active		
Х	1	0	1	0	Active		
0	0	Х	High Im	Driver Disabled			
1	0	Х	High Im	Shutdown			

RECEIVING						
	INPUTS		OUTPUTS	MODE		
RE	DE	A-B	RO	WODE		
0	Х	≥ -10mV	1	Active		
0	Х	≤ -200mV	0	Active		
0	Х	Open/Shorted	1	Active		
1	1	Х	High Impedance	Receiver Disabled		
1	0	Х	High Impedance	Shutdown		

X = Don't care

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Detailed Description

The MAX14783E is a 3.3V/5V ESD-protected RS-485/ RS-422 transceiver intended for high-speed, half-duplex communications. Integrated hot-swap functionality eliminates false transitions on the bus during power-up or hot insertion.

The device features fail-safe receiver inputs guaranteeing a logic-high receiver output when inputs are shorted or open. The IC has a 1-unit load receiver input impedance, allowing up to 32 transceivers on the bus.

True Fail Safe

The MAX14783E guarantees a logic-high receiver output when the receiver inputs are shorted or open, or when they are connected to a terminated transmission line with all drivers disabled. If the differential receiver input voltage (A–B) is greater than or equal to -10mV, RO is logic-high.

Driver Single-Ended Operation

The A and B outputs can either be used in the standard differential operating mode, or can be used as singleended outputs. Since the A and B driver outputs swing rail-to-rail, they can individually be used as standard TTL logic outputs.

Hot-Swap Capability

Hot-Swap Inputs

When circuit boards are inserted in a hot or powered backplane, disturbances on the enable inputs and differential receiver inputs can lead to data errors. Upon initial circuit board insertion, the processor undergoes its power-up sequence. During this period, the processor output drivers are high impedance and are unable to drive the DE and \overline{RE} inputs of the MAX14783E to a defined logic level. Leakage currents up to 10µA from the high-impedance outputs of a controller could cause DE and \overline{RE} to drift to an incorrect logic state. Additionally, parasitic circuit board capacitance could cause coupling of V_{CC} or GND to DE and \overline{RE} . These factors could improperly enable the driver or receiver. The MAX14783E features integrated hot-swap inputs that help to avoid these potential problems.

When $V_{\underline{CC}}$ rises, an internal pulldown circuit holds DE low and \overline{RE} high. After the initial power-up sequence, the pulldown circuit becomes transparent, resetting the hot-swap-tolerable inputs.

Hot-Swap Input Circuitry

The DE and $\overline{\text{RE}}$ enable inputs feature hot-swap capability. At the input, there are two nMOS devices, M1 and M2 (Figure 9). When V_{CC} ramps from 0V, an internal 10µs timer turns on M2 and sets the SR latch that also turns

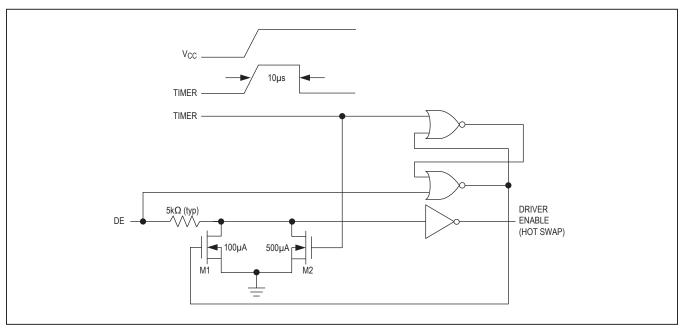


Figure 9. Simplified Structure of the Driver Enable (DE) Pin

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

on M1. Transistors M2 (a 500 μ A current sink) and M1 (a 100 μ A current sink) pull DE to GND through a 5k Ω (typ) resistor. M2 is designed to pull DE to the disabled state against an external parasitic capacitance up to 100pF that can drive DE high. After 10 μ s, the timer deactivates M2 while M1 remains on, holding DE low against three-state leakages that can drive DE high. M1 remains on until an external source overcomes the required input current. At this time, the SR latch resets and M1 turns off. When M1 turns off, DE reverts to a standard, high-impedance CMOS input. Whenever V_{CC} drops below 1V, the hot-swap input is reset.

A complementary circuit employing two pMOS devices pulls $\overline{\text{RE}}$ to $\text{V}_{CC}.$

±35kV ESD Protection

ESD protection structures are incorporated on all pins to protect against electrostatic discharges encountered during handling and assembly. The driver outputs and receiver inputs of the MAX14783E have extra protection against static electricity. The ESD structures withstand high ESD in all states: normal operation, shutdown, and powered down. After an ESD event, the MAX14783E keeps working without latch-up or damage.

ESD protection can be tested in various ways. The transmitter outputs and receiver inputs of the MAX14783E are characterized for protection to the following limits:

- ±35kV HBM
- ±20kV using the Air-Gap Discharge method specified in IEC 61000-4-2
- ±12kV using the Contact Discharge method specified in IEC 61000-4-2

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model (HBM)

Figure 10 shows the HBM, and Figure 11 shows the current waveform it generates when discharged into a low-impedance state. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a $1.5k\Omega$ resistor.

IEC 61000-4-2

The IEC 61000-4-2 standard covers ESD testing and performance of finished equipment. However, it does not specifically refer to integrated circuits. The MAX14783E helps in designing equipment to meet IEC 61000-4-2 without the need for additional ESD protection components.

The major difference between tests done using the HBM and IEC 61000-4-2 is higher peak current in IEC 61000-4-2 because series resistance is lower in the IEC 61000-4-2 model. Hence, the ESD withstand voltage measured to IEC 61000-4-2 is generally lower than that measured using the HBM.

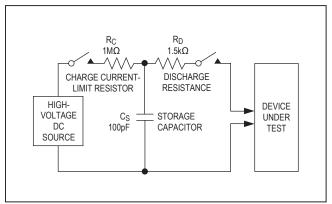


Figure 10. Human Body ESD Test Model

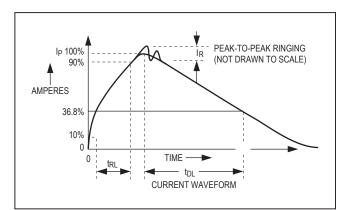


Figure 11. Human Body Current Waveform

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Figure 12 shows the IEC 61000-4-2 model, and Figure 13 shows the current waveform for IEC 61000-4-2 ESD Contact Discharge test.

Applications Information

Driver Output Protection

Two mechanisms prevent excessive output current and power dissipation caused by faults or by bus connection. The first, a current limit on the output stage provides immediate protection against short circuits over the whole common-mode voltage range. The second, a thermal-shutdown circuit, forces the driver outputs into a high-impedance state if the die temperature exceeds +160°C (typ).

Low-Power Shutdown Mode

Low-power shutdown mode is initiated by bringing \overline{RE} high and DE low. In shutdown, the devices draw less than 10µA of supply current.

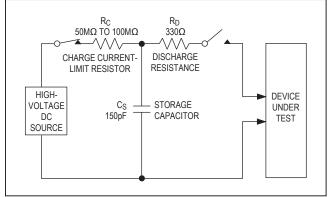


Figure 12. IEC 61000-4-2 ESD Test Model

 $\overline{\text{RE}}$ and DE can be connected together and driven simultaneously. The MAX14783E is guaranteed not to enter shutdown if $\overline{\text{RE}}$ is high and DE is low for less than 50ns. If the inputs are in this state for at least 800ns (max), the device is guaranteed to enter shutdown.

Typical Applications

The MAX14783E transceiver is designed for bidirectional data communications on multipoint bus transmission lines. Figure 14 shows a typical network application circuit. To minimize reflections, terminate the line at both ends with its characteristic impedance and keep stub lengths off the main line as short as possible.

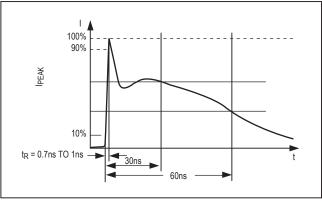


Figure 13. IEC 61000-4-2 ESD Generator Current Waveform

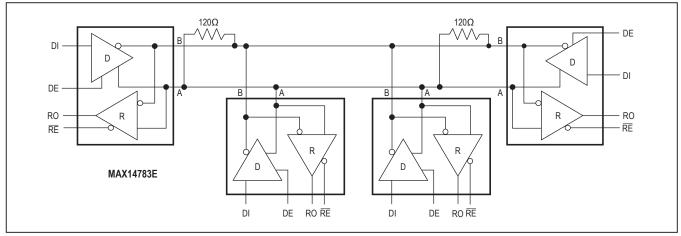


Figure 14. Typical Half-Duplex RS-485 Network

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Ordering Information

PART	SUPPLY RANGE	DATA RATE (MAX)	TEMP RANGE	PIN-PACKAGE	
MAX14783EEUA+	3.0V to 5.5V	30Mbps	-40°C to +85°C	8 µMAX	
MAX14783EESA+	3.0V to 5.5V	40Mbps	-40°C to +85°C	8 SO	
MAX14783EATA+	3.0V to 5.5V	42Mbps	-40°C to +125°C	8 TDFN-EP*	
MAX14783EASA+	3.0V to 3.6V	42Mbps	-40°C to +125°C	8 SO	
MAX 14783EASA+	3.0V to 5.5V	16Mbps			
MAX14783EAUA+	3.0V to 3.6V	42Mbps	-40°C to +125°C	8 µMAX	
WAA 14703EAUAT	3.0V to 5.5V	6Mbps	-40 C to +125 C	ο μινικλ	

+Denotes lead(Pb)-free/RoHS-compliant package.

*EP = Exposed paddle.

Chip Information

PROCESS: BICMOS

High-Speed 3.3V/5V RS-485/RS-422 Transceiver with ±35kV HBM ESD Protection

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/13	Initial release	—
1	1/15	Updated page 1 content	1
2	7/20	Updated the Benefits and Features and Electrical Characteristics sections	1, 3

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